

AW318A Datasheet

Zhuhai Jieli Technology Co.,LTD

Version 1.1

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Revision History

Date	Revision	Description
2024.04.12	V1.0	Initial Release
2024.07.04	V1.1	Update IC Marking Information

Table of Contents

Revision History	1
Table of Contents	2
AW318A Features	3
1 Block Diagram	4
2 Pin Definition	5
2.1 Pin Assignment	5
2.2 Pin Description	6
3 Electrical Characteristics	7
3.1 Absolute Maximum Ratings	7
3.2 ESD Ratings	7
3.3 PMU Characteristics	7
3.4 IO Characteristics	7
3.5 BT Characteristics	8
4 Package Information	9
4.1 SOP8	9
5 IC Marking Information	10
6 Solder-Reflow Condition	11

AW318A Features

SYSTEM

- 32bit CPU 160MHz
- Support MATH/AES128
- I-cache
- Support EMU
- On-chip SRAM 32kbyte
- Support MPU
- Support UDMA
- Built-In Flash
- 24MHz crystal oscillator
- Internal low jitter low power RC oscillator
- Internal PLL

Bluetooth

- BLE5.4 +2.4GHz-Proprietary (QDID 223418)
- Support AoA Transmitter
- Support long range BLE
- Maximum transmitting power 8dBm
- Receiver sensitivity
 - ❖ -92dBm @BLE-1Mbps
 - ❖ -89dBm @BLE-2Mbps
 - ❖ -95dBm @BLE-S2
 - ❖ -100dBm @BLE-S8

Peripherals

- 1 x Full speed USB
- 4 x Multi-function 32bit timer
- 1 x IR RX/TX
- 1 x UART interface
- 1 x I²C Master/Slave interface
- 2 x SPI Master/Slave interface
- 1 x QDEC
- 3 x MCPWM
- 2 x LEDC
- 1 x 10bit ADC(3 Channel)
- 2 x GPIO Support function remapping

PMU

- Support temperature sensor
- VPWR range 2.7V to 5.5V
- IOVDD range 1.8V to 3.6V
- Deep sleep mode (IOVDD @3.0V)
 - ❖ 170nA (External wakeup)
 - ❖ 1.37uA (32kHz RC OSC+wakeup)
 - ❖ 2.9uA (32kHz RC OSC+wakeup+16k retention SRAM)

Packages

- SOP8

Temperature

- Operating temperature
 - TC = -20℃ to +85℃ (standard range)
 - TC = -40℃ to +105℃ (extended range)
- Storage temperature -65℃ to +150℃

Applications

- Mouse devices
- Non-audio remote controller
- Selfie stick
- Page turner
- Adaptive USB
- Bluetooth module
- Price tag and other diversified IOT product

1 Block Diagram

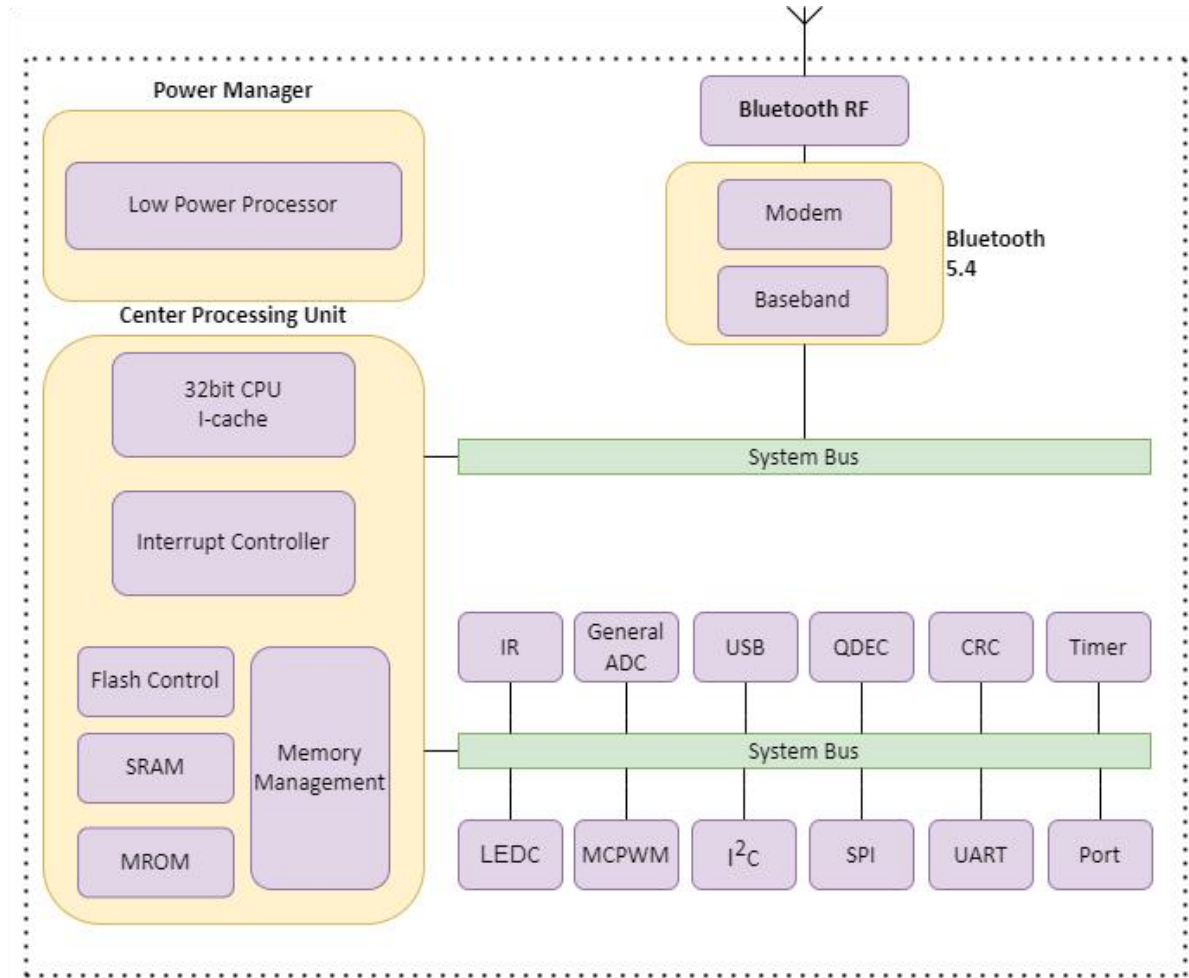


Figure 1-1 AW318A Block Diagram

2 Pin Definition

2.1 Pin Assignment

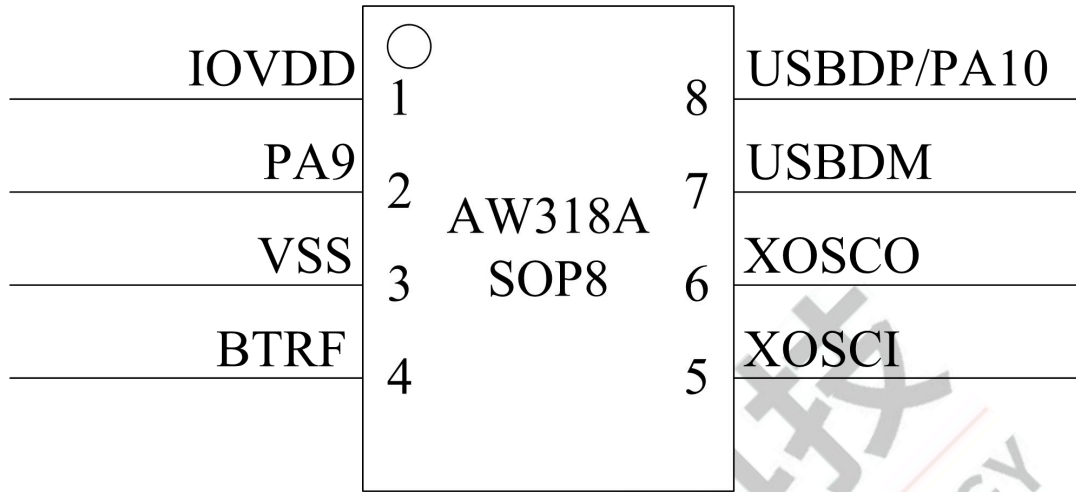


Figure 2-1 AW318A Pin Assignment

2.2 Pin Description

Table 2-2-1 AW318A Pin Description

Pin No.	Name	Type	IO Initial State	Description
1	IOVDD	P	--	IO Power
2	PA9	I/O	Z	LVD(External Low Voltage Detection Input) ADC9(ADC Input Channel 9) SPI0_DAT3B
3	VSS	G	--	Ground
4	BTRF	RF	--	Bluetooth RF Antenna
5	XOSCI	I	--	Crystal Oscillator Input
6	XOSCO	O	--	Crystal Oscillator Output
7	USBDM	I/O	15kΩ Pull-down	ADC13(ADC Input Channel 13)
8	USBDP	I/O	15kΩ Pull-down	ADC14(ADC Input Channel 14)
	PA10	I/O	Z	ADC10(ADC Input Channel 10)

Note

- 1.IO initial state abbreviations Z--High resistance, H--High level, L--Low level, X--May be changed during power on.
- 2.Timer, IR,MCPWM, QDEC, UART, LEDC, I²C, SPI1 functions can be remapped to any I/O.

Table 2-2-2 Pin Types Description

Pin Type	Description	Pin Type	Description
P	Power	I/O	Input or Output
G	Ground	I	Input
RF	RF antenna	O	Output

3 Electrical Characteristics

3.1 Absolute Maximum Ratings

Table 3-1 Absolute Maximum Ratings

Symbol	Parameter	Min	Max	Unit
Topt	Operating temperature	-20	+85	°C
Tstg	Storage temperature	-65	+150	°C
IOVDD		-0.3	3.6	V
GPIO	Input voltage of GPIO (except PA7)	-0.3	3.6	V

Note

1.Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device.

3.2 ESD Ratings

Table 3-2 ESD Ratings

Parameter	Typ	Test pin	Reference standard
Human Body Mode	±8kV	All pins	JEDEC EIA/JESD22-A114
Machine Mode	±400V	All pins	JEDEC EIA/JESD22-A115
Charge Device Model	±2kV	All pins	ANSI/ESDA/JEDEC JS-002-2022

3.3 PMU Characteristics

Table 3-3-1 PMU Characteristics under IOVDD supply

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
IOVDD	Power supply	--	1.8	--	3.6	V

3.4 IO Characteristics

Table 3-4 IO Characteristics

Input Characteristics						
Symbol	Parameter	Conditions	IO	Min	Max	Unit
V _{IL}	Low-Level Input Voltage	IOVDD = 3.0V	PA9,PA10	-0.3	1.4	V
V _{IH}	High-Level Input Voltage	IOVDD = 3.0V	PA9,PA10 USB DP USB DM	1.7	3.3	V
Output Characteristics						
Symbol	Parameter	Conditions	IO	Typ		Unit
I _{OL}	Output Current	IOVDD = 3.0V V _{output} = 0.3V	PA9,PA10	3(HD=0) 9(HD=1) 21(HD=2)		mA

				54(HD=3)	
		IOVDD = 3.0V Voutput = 0.3V	USBDP USBDM	8	mA
I _{OH}	Output Current	IOVDD = 3.0V Voutput = 2.7V	PA9,PA10	3(HD=0) 9(HD=1) 21(HD=2) 54(HD=3)	mA
		IOVDD = 3.0V Voutput = 2.7V	USBDP USBDM	8	mA
Internal Resistance Characteristics					
Symbol	Parameter	Conditions	IO	Typ	Unit
R _{pu}	Pull-up Resistance	IOVDD = 3.0V	PA9,PA10	10k(PU=1) 100k(PU=2) 1M(PU=3)	Ω
		IOVDD = 3.0V	USBDP	1.5k	Ω
		IOVDD = 3.0V	USBDM	180k	Ω
R _{pd}	Pull-down Resistance	IOVDD = 3.0V	PA9,PA10	10k(PD=1) 100k(PD=2) 1M(PD=3)	Ω
		IOVDD = 3.0V	USBDP USBDM	15k	Ω

Note

1.Internal pull-up/pull-down resistance accuracy ±20%.

3.5 BT Characteristics

3.5.1 Transmitter

Table 3-5-1 Transmitter characteristics

Parameter	Conditions	Min	Typ	Max	Unit
Maximum RF Transmit Power	BLE-1Mbps	--	7	8	dBm

3.5.2 Receiver

Table 3-5-2 Receiver characteristics

Parameter	Conditions	Min	Typ	Max	Unit
Sensitivity	BLE-1Mbps	--	-92	--	dBm
	BLE-2Mbps	--	-89	--	dBm
	BLE-S2	--	-95	--	dBm
	BLE-S8	--	-100	--	dBm

4 Package Information

4.1 SOP8

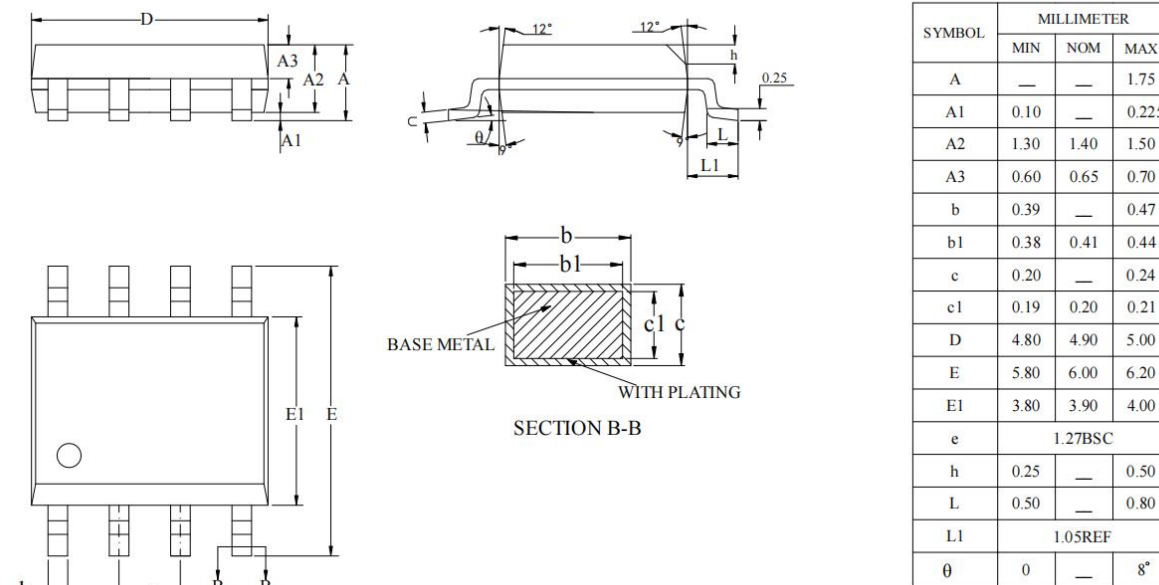


Figure 4-1 AW318A Package

5 IC Marking Information

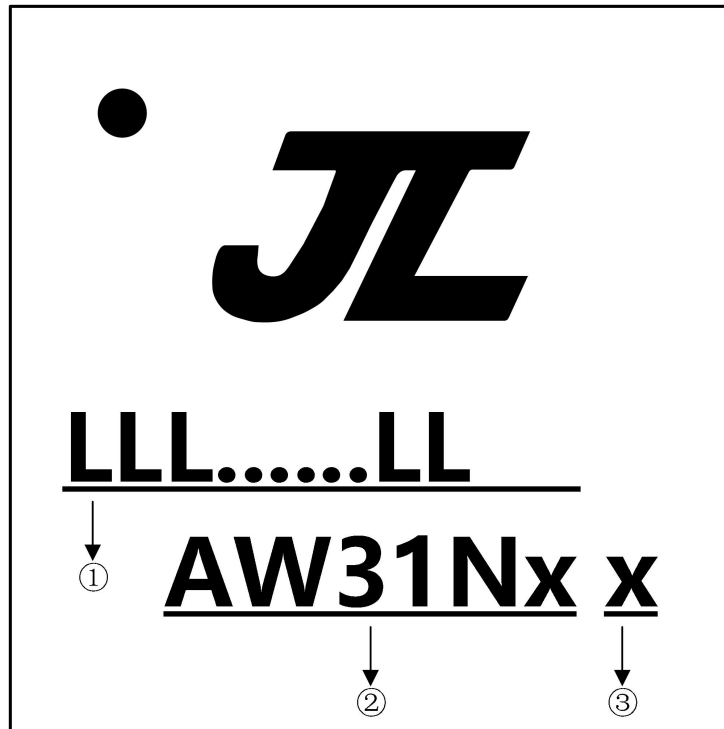


Figure 5-1 AW318A Package Outline

- ① LLL.....LL LOT No. , It contains 7 to 18 alphanumerics
- ② AW31Nx Chip Model
- ③ x Built-in flash size
 - 0 No Flash Memory
 - 2 2Mbit Flash
 - 4 4Mbit Flash

6 Solder-Reflow Condition

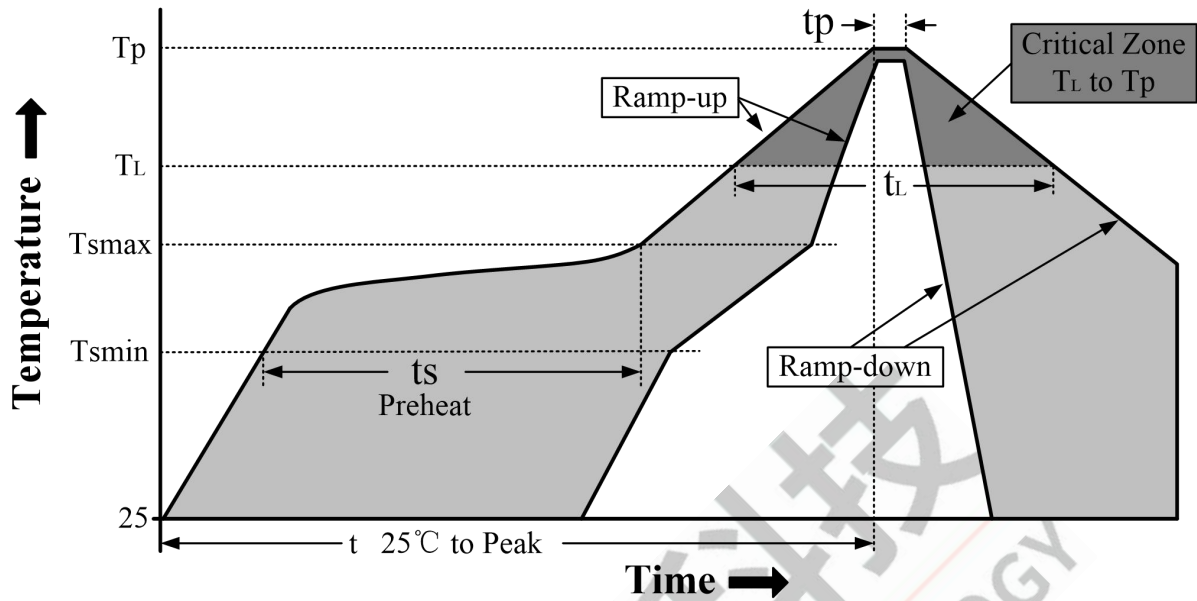


Figure 6-1 Classification Reflow Profile

Table 6-1 Classification Profiles

Profile Feature		Sn-Pb Eutectic Assembly	Pb-Free Assembly
Preheat/Soak	Temperature Min (T_{smin})	100°C	150°C
	Temperature Max (T_{smax})	150°C	200°C
	Time (t_s) from (T_{smin} to T_{smax})	60-120 seconds	60-180 seconds
Average ramp-up rate (T_{smax} to T_p)		3°C/second max	3°C/second max
Liquidus temperature (T_L)		183°C	217°C
Time (t_L) maintained above T_L		60-150 seconds	60-150 seconds
Peak package body temperature (T_p)		See Table 6-2	See Table 6-3
Time within 5°C of actual Peak Temperature (t_p) ²		10-30 seconds	20-40 seconds
Ramp-down rate (T_p to T_L)		6°C/second max	6°C/second max
Time 25°C to peak temperature		6 minutes max	8 minutes max

Note

- 1.All temperatures refer to topside of the package, measured on the package body surface
- 2.Time within 5°C of actual peak temperature (t_p) specified for the reflow profiles is a "supplier" and "user" maximum.

Table 6-2 SnPb Classification Temperature

Package Thickness	Volume mm ³ < 350	Volume mm ³ ≥ 350
<2.5 mm	240 +0/-5°C	225 +0/-5°C
≥2.5 mm	225 +0/-5°C	225 +0/-5°C

Table 6-3 Pb-free - Classification Temperature

Package Thickness	Volume mm ³ < 350	Volume mm ³ 350 - 2000	Volume mm ³ > 2000
< 1.6mm	260°C	260°C	260°C
1.6 mm - 2.5mm	260°C	250°C	245°C
> 2.5mm	250°C	245°C	245°C

Note

1.*Tolerance The device manufacturer/supplier shall assure process compatibility up to and including the stated classification temperature (this means Peak reflow temperature +0°C.For example 260°C+0°C)at the rated MSL level.